

# Gan And Related Materials Vol 2.pdf

## [Redistribution of implanted dopants in GaN | SpringerLink](#)

Wed, 12 Jun 2019 07:25:00 GMT

Donor (S, Se, and Te) and acceptor (Mg, Be, and C) dopants have been implanted into GaN at doses of  $3\text{--}5 \times 10^{14} \text{ cm}^{-2}$  and annealed at temperatures up to  $1450^\circ\text{C}$ . No redistribution of any of the elements...

## [Shallow and Deep Level Defects in GaN | MRS Online ...](#)

Sun, 12 Aug 2018 08:46:00 GMT

Gallium nitride - Wikipedia

## [A Review of Dry Etching of GaN and Related Materials ...](#)

Mon, 20 May 2019 11:48:00 GMT

A Review of Dry Etching of GaN and Related Materials - Volume 5 Issue 1 - S.J. Pearton, R. J. Shul, Fan Ren

## [GaN, AlN, InN and Related Materials - Assets](#)

Sat, 08 Jun 2019 10:00:00 GMT

MATERIALS RESEARCH SOCIETY SYMPOSIUM PROCEEDINGS VOLUME 892 GaN, AlN, InN and Related Materials Symposium held November 28-December 2, 2005, Boston, Massachusetts, U.S.A.

## [IEEE TRANSACTIONS ON DEVICE AND MATERIALS RELIABILITY, VOL ...](#)

Fri, 17 May 2019 22:36:00 GMT

IEEE TRANSACTIONS ON DEVICE AND MATERIALS RELIABILITY, VOL. 8, NO. 2, JUNE 2008 323 A Review on the Reliability of GaN-Based LEDs Matteo Meneghini, StudentMember,IEEE, Lorenzo-Roberto Trevisanello,

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